#### **DATA SHEET**



# SILICON POWER TRANSISTORS 2SA1615, 1615-Z

# PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1615 and 1615-Z are available for the large current control in small dimension due to the low saturation and are ideal for high-efficiency DC/DC converters due to the fast switching speed.

#### **FEATURES**

· Large current capacity:

IC(DC): -10 A, IC(pulse): -15 A

• High hee and low collector saturation voltage:

hfe = 200 MIN. (@Vce = -2.0 V, Ic = -0.5 A)

 $V_{CE(sat)} \le -0.25 \text{ V } (@Ic = -4.0 \text{ A}, IB = -0.05 \text{ A})$ 

#### **QUALITY GRADES**

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	-30	V
Collector to emitter voltage	VCEO	-20	V
Emitter to base voltage	V <sub>EBO</sub>	-10	V
Collector current (DC)	Ic(DC)	-10	Α
Collector current (pulse)	IC(pulse)*	-15	Α
Base current (DC)	I <sub>B(DC)</sub>	-0.5	Α
Total power dissipation	P <sub>T</sub> (T <sub>a</sub> = 25°C)**	1.0	W
Total power dissipation	P⊤ (T <sub>c</sub> = 25°C)	15	W
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

<sup>\*</sup> PW  $\leq$  10 ms, duty cycle  $\leq$  50%

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

<sup>\*\*</sup> Printing board mounted



#### **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

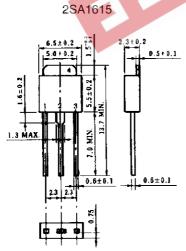
Paran	Parameter Symbol Conditions		MIN.	TYP.	MAX.	Unit	
Collector cutof	ff current	I <sub>CBO</sub> V <sub>CB</sub> = -20 V, I <sub>E</sub> = 0				-1.0	μΑ
Emitter cutoff current		ІЕВО	$V_{EB} = -8.0 \text{ V}, \text{ Ic} = 0$			-1.0	μΑ
DC current ga	in	h <sub>FE1</sub> *	Vce = -2.0 V, Ic = -0.5 A	200		600	
DC current gain		hFE2*	Vce = -2.0 V, Ic = -4.0 A	160			
Collector saturation voltage		V <sub>CE(sat)</sub> *	Ic = -4.0 A, I <sub>B</sub> = -0.05 A		-0.2	-0.25	V
Base saturation	n voltage	V <sub>BE(sat)</sub> *	Ic = -4.0 A, I <sub>B</sub> = -0.05 A		-0.9	-1.2	V
Gain bandwidt	th product	f⊤	Vce = -5.0 V, IE = 1.5 A		180		MHz
Output capacity		Cob	VcB = -10 V, IE = 0, f = 1.0 MHz		220		pF
Turn-on time		ton	$I_C = -5.0 \text{ A}, I_{B1} = -I_{B2} = 0.125 \text{ A},$		80		ns
Storage time		tstg	$R_L = 2.0 \Omega$ , $V_{CC} \cong -10 V$		300		ns
Fall time t <sub>f</sub>		t <sub>f</sub>			60		ns
* Pulse test PW ≤ 350 μs, duty cycle ≤ 2% <b>hFE CLASSIFICATION</b> Marking L K  h <sub>FE2</sub> 200 to 400 300 to 600							
Marking	L		K 300 to 600				
h <sub>FE2</sub>	200 to 400	) 3					
DACKACE DRAWING (MNIT: 1999)							

<sup>\*</sup> Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2%

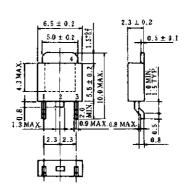
#### **hfe CLASSIFICATION**

Marking	L	K	
h <sub>FE2</sub>	200 to 400	300 to 600	

### PACKAGE DRAWING (UNIT: mm)



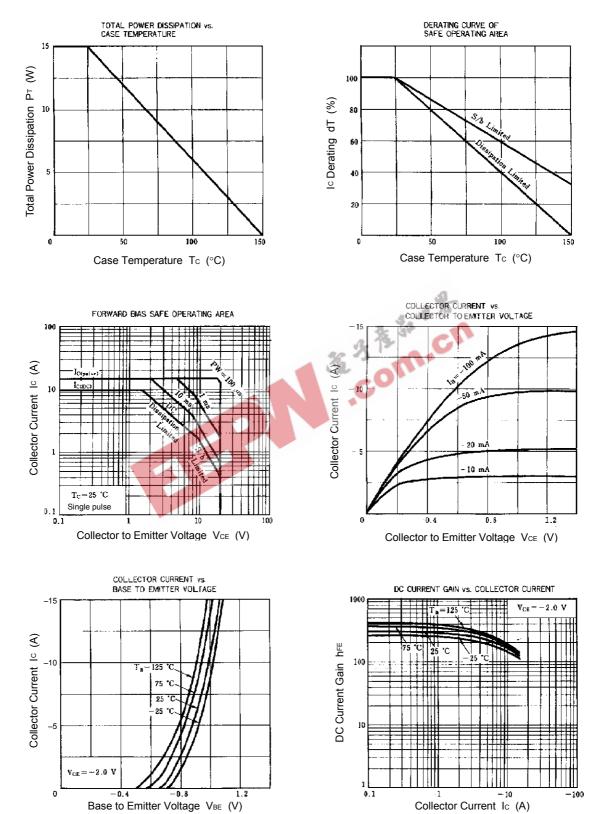
#### 2SA1615-Z



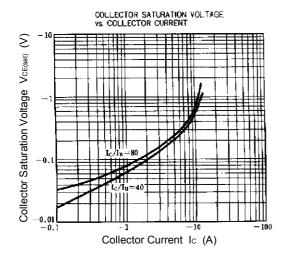
- Electrode Connection
- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector (fin)

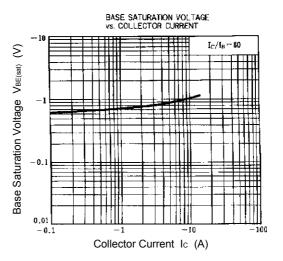
## NEC

#### TYPICAL CHARACTERISTICS (Ta = 25 °C)

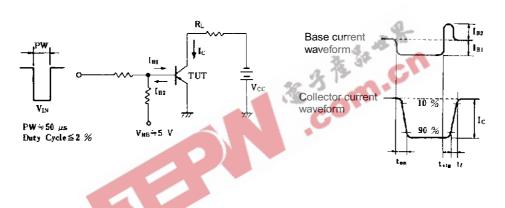


3





#### SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



[MEMO]



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